	COUNT	DESCRIPTION	OF REVISIONS	BY	CHKD	DATE		CC	UNT	DESCRIPTION OF RE	VISIONS	BY	CHKD	DA	\TE	
APPLICABLE STANDARD																
		OPERATING TEMPERATURE RAI		-55°C TO +85°C (note1) STO					ORAGE -10℃		TO +6	O +60℃				
R	ATING	VOLTAGE	illa.	30 V AC/DC APF					PLICABLE	BM23F	BM23FR0.6-16DS-0.35V(/(**)		
		CURRENT							NNECTOR BIVIZED NO. 0 TODG							
				SPECIFICATION					<u> </u>	l						
	ITEM TEST METHOD REQUIREMENTS									ОТ	АТ					
C	ONST	RUCTION			.01 1412					, riegoni				<u> </u>	7	
GENERAL EXAMINATION			CONFIRMED VISUALLY AND BY MEASURING INSTRUMENT.						ACCORDING TO DRAWING.				х	х		
MARKING			CONFIRMED VISUALLY.											Х	Х	
ELECTRICAL CHARACTERISTICS																
©ONTACT RESISTANCE			20mV AC OR LESS 1kHz, 1mA						100mΩ MAX				х	_		
βĘ	SULATI	ON RESISTANCE	100V DC							50MΩ MIN				Х	_	
ξĀ	OĻTAGE	PROOF	100V AC FOR	100V AC FOR 1min.							NO FLASHOVER OR BREAKDOWN				_	
₹/	ECH/	ANICAL CHAF	RACTERIST	CS						•						
MSERTION AND			MEASURED BY APPLICABLE CONNECTOR.						INSERTION FORCE - N MAX				, ,			
WHDRAWAL FORCES									EXTRACTION FORCE - N MIN				Х	_		
MECHANICAL PERATION			10 TIMES INSERTIONS AND EXTRACTIONS.						① CONTACT RESISTANCE: 100mΩ MAX ② NO DAMAGE, CRACK OR LOOSENESS OF PATRS.				x	_		
enab or furi																
Representative to the local labration of the labration of			FREQUENCY 10 TO 55 TO 10 Hz, APPROX 5min SINGLE AMPLITUDE 0.75mm, 10CYCLES, FOR 3 DIRECTIONS.						NO ELECTRICAL DISCONTINUITY OF 1µs. NO DAMAGE, CRACK OR LOOSENESS OF PARTS.				x	ı		
															<u>≅ ;</u> SHÐCK	
ping Sres			FOR 3 DIRECTIONS.						② NO DAMAGE, CRACK OR LOOSENESS				х	_		
g	<u>re</u>									OF PARTS.						
U	<u> REVIDU</u>	JINIMENTAL C	HARACTER	ISTIC	S											
潜A型D CHANGE OF TEMPERATURE -55 → +85℃									① CONTACT RESISTAN							
ŌEMPERATURE O O C			TIME 30 → 30 min UNDER 5 CYCLES.							② INSULATION RESISTANCE: 50MΩ MIN ③ NO DAMAGE, CRACK OR LOOSENESS OF PARTS.				x -	-	
E OR BAMP HEAT BAMP HEAT OR DEADY STATE) OR OR OR OR			(RELOCATION TIME TO CHAMBER: WITHIN2~3 MIN)													
<u>9</u>	A∰MP HE	AT	EXPOSED AT	EXPOSED AT 40±2°C, 90 TO 95%, 96h.						① CONTACT RESISTANCE: 100mΩ MAX						
STEADY STATE)									② INSULATION RESISTANCE: 25MΩ MIN ③ NO DAMAGE, CRACK OR LOOSENESS				х	l _ '		
ne a																
<u> 11</u>	<u>10</u>	DIOVIDE	EVPOOED IN SE DOM FOR ONL SESS TELESCOLO						OF PARTS.	IOE: 1	00=0	MAY				
E SUZPHUR DIOXIDE SO SO SO SO SO SO SO SO SO SO			EXPOSED IN 25 PPM FOR 96h, 25℃, 75±5%RH. (Test standard : JIS C 60068)							① CONTACT RESISTANCE: 100mΩ MAX				х	_	
ase			(1000 otalidala - 010 o oodoo)						^							
b III			•													

DRAWING FOR REFERENCE

This is subjet to change without notice

REMARKS	DRAWN	DESIGNI	ED CHECKED	APPROVED	RELEASED			
Note 1; INCLUDE THE TEMPERATURE RIS	S.H.JUNG	S.H.JUI	NG H.W.JO	T.S.KANG	ENG 17.05.08			
Unless otherwise specified, refer to JIS C 5-	17.05.08	17.05.0	17.05.08	17.05.08	DEPT			
Note QT: QUALIFICATION TEST AT: ASSURANCE TEST X: APPLICABLE TEST								
	OATION OUE		PART NO.					
HIROSE KOREA CO.,LTD.	SPECIFI	CATION SHE	ΕI	BM23FR0.6-16DP-0.35V(895)				

CODE NO.(OLD) DRAWING NO.
CL SLC4-632065

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